TOSHIBA Field Effect Transistor Silicon N-Channel MOS Type (U-MOSVI-H)

TPC8045-H

Switching Regulator Applications Motor Drive Applications DC-DC Converter Applications

- Small footprint due to a small and thin package
- · High-speed switching
- Small gate charge: Q_{SW} = 23 nC (typ.)
- Low drain-source ON-resistance:

 $R_{DS(ON)} = 2.7 \text{ m}\Omega \text{ (typ.)}$

- High forward transfer admittance: |Y_{fs}| = 67 S (typ.)
- Low leakage current: $I_{DSS} = 10 \,\mu\text{A} \,(\text{max}) \,(\text{V}_{DS} = 40 \,\text{V})$
- Enhancement mode: V_{th} = 1.3 to 2.3 V (V_{DS} = 10 V, I_D = 1 mA)

Absolute Maximum Ratings (Ta = 25°C)

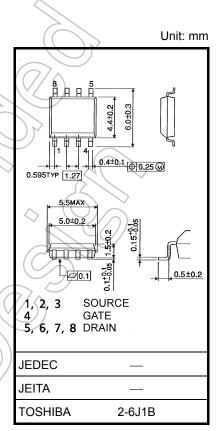
Characteristic		Symbol	Symbol Rating	
Drain-source voltage		V_{DSS}	40	V
Drain-gate voltage (R _{GS} = 20 kΩ)		V _{DGR}	40	y
Gate-source voltage		V _{GSS}	±20	<
Drain current	DC (Note 1)	ID	18	A
	Pulsed (Note 1)	†DP	72	^
Drain power dissipation (t = 10 s) (Note 2a)		PD	1.9	W
Drain power dissipation (t = 10 s) (Note 2b)		PD	1.0	w
Single-pulse avalanche energy (Note 3)		EAS	150	mJ
Avalanche current		IAR	18	Α
Repetitive avalanche energy (Tc=25°C) (Note 4)		E _{AR}	0.06	mJ
Channel temperature		Tch	150	°C
Storage temperature range		T _{stg}	-55 to 150	°C

Note: For Notes 1 to 4, refer to the next page.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the

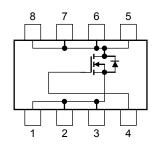
reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

This transistor is an electrostatic-sensitive device. Handle with care.



Weight: 0.085g (typ.)

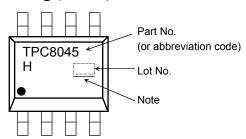
Circuit Configuration



Thermal Characteristics

Characteristic	Symbol	Max	Unit
Thermal resistance, channel to ambient $(t = 10 \text{ s})$ (Note 2a)	R _{th (ch-a)}	65.8	°C/W
Thermal resistance, channel to ambient (t = 10 s) (Note 2b)	R _{th (ch-a)}	125	°C/W

Marking (Note 5)



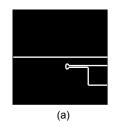
Note: A line under a Lot No. identifies the indication of product Labels [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

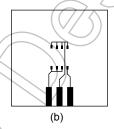
Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: (a) Device mounted on a glass-epoxy board (a)

(b) Device mounted on a glass-epoxy board (b)



FR-4 25.4 × 25.4 × 0.8 (Unit: mm)

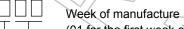


FR-4 $25.4 \times 25.4 \times 0.8$ (Unit: mm)

Note 3: $V_{DD} = 24 \text{ V}$, $T_{ch} = 25 ^{\circ}\text{C}$ (initial), $L = 500 \mu\text{H}$, $R_G = 25 \Omega$, $I_{AR} = 18 \text{ A}$

Note 4: Repetitive rating: pulse width limited by maximum channel temperature

Note 5: * Weekly code: (Three digits)



(01 for the first week of the year, continuing up to 52 or 53)

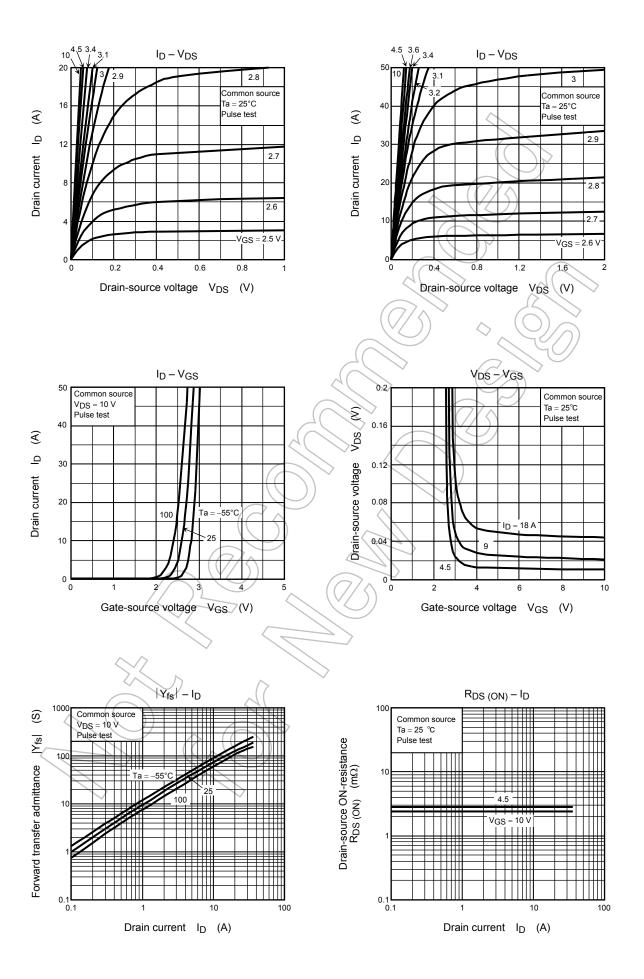
Year of manufacture (The last digit of the year)

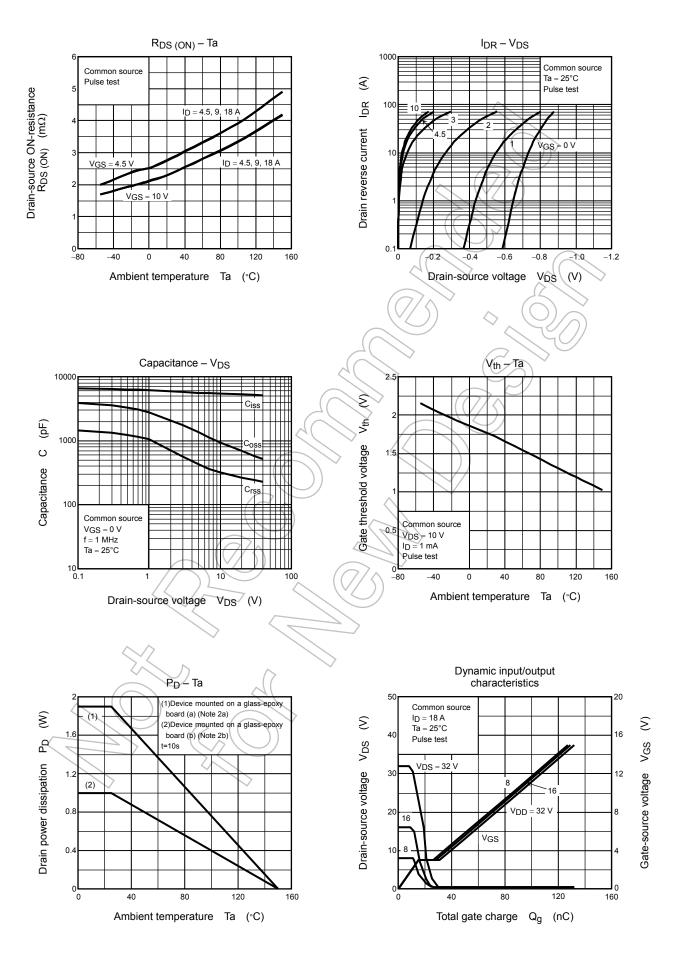
Electrical Characteristics (Ta = 25°C)

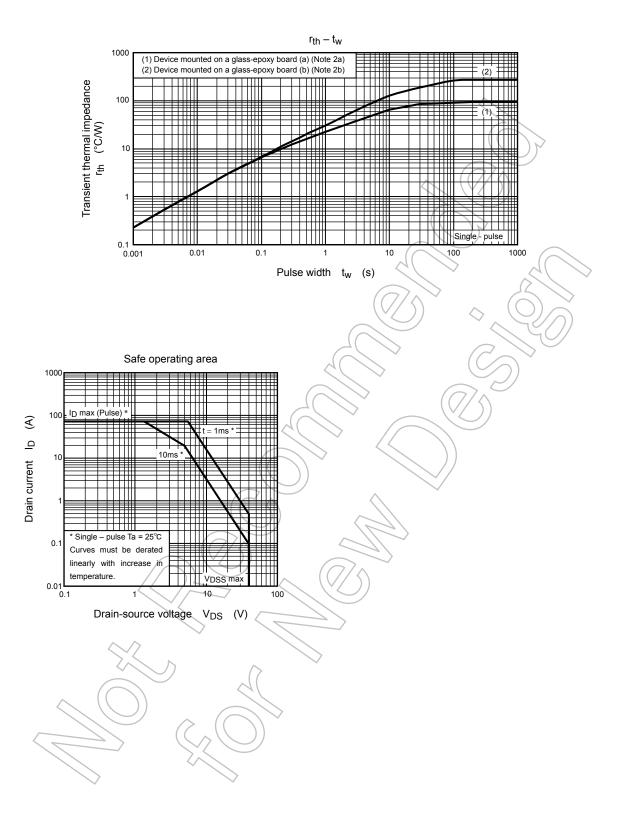
Ch	aracteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cur	rent	I _{GSS}	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±100	nA
Drain cutoff curre	nt	I _{DSS}	V _{DS} = 40 V, V _{GS} = 0 V		_	10	μА
Drain-source breakdown voltage		V (BR) DSS	$I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$	40	_	_	V
		V (BR) DSX	$I_D = 10 \text{ mA}, V_{GS} = -20 \text{ V}$	25	_	_	V
Gate threshold vo	oltage	V _{th}	$V_{DS} = 10 \text{ V}, I_{D} = 1 \text{ mA}$	1.3) /_	2.3	V
Drain-source ON-resistance		Б	V _{GS} = 4.5 V, I _D = 9 A) <u> </u>	3.2	4.4	- mΩ
		R _{DS} (ON)	V _{GS} = 10 V, I _D = 9 A	\mathcal{P}	2.7	3.9	
Forward transfer	admittance	Y _{fs}	V _{DS} = 10 V, I _D = 9 A	33.5	67	_	S
Input capacitance		C _{iss}		_	5800	7540	
Reverse transfer	capacitance	C _{rss}	$V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	_	305	445	pF
Output capacitan	ce	Coss		/	950	\rightarrow	
Gate resistance		rg	$V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	-6	1.0	1.5	Ω
Switching time	Rise time	t _r	10 V □ I _D = 9 A	4	6.4) _	
	Turn-on time	t _{on}	VGS OV L	$\sqrt{2}$	16	_	no
	Fall time	t _f	2.2.2.2.2.2.2.2.2.2.2.2.2.2.2.2.2.2.2.		16	_	ns
	Turn-off time	t _{off}	V _{DD} ≈ 20 V Duty ≤ 1%, t _w = 10 μs	_	76	_	
Total gate charge (gate-source plus gate-drain)		Qg	$V_{DD} \approx 32 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 18 \text{ A}$	_	90	_	
			$V_{DD} \approx 32 \text{ V}, V_{GS} = 5 \text{ V}, I_{D} = 18 \text{ A}$	_	48	_	
Gate-source char	ge 1 (Q _{gs1}			15		nC
Gate-drain ("Miller") charge		Q_{gd}	$V_{DD} \approx 32 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 18 \text{ A}$		16		
Gate switch charge		Q _{SW}		_	23	_	

Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Peak forward current Pulse (Note 1)	I _{FP}	> -	_	_	72	Α
Forward voltage (diode)	V _{DSF}	I _{DR} = 18 A, V _{GS} = 0 V			-1.2	V







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